

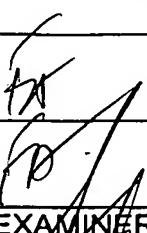
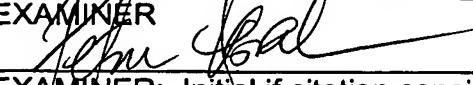
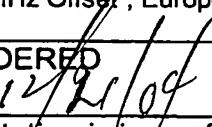
FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))				Attorney Docket No.: P2001,0373 Appl. No.: Applicant: JUDITH MAGET Filing Date: November 13, 2003 Group Art Unit:																																																																																			
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	Tiebout, M.: "A Fully Integrated 1.3GHz VCO for GSM in 0.25µm Standard CMOS with a Phasenoise of -142dBc/Hz at 3MHz Offset", European Microwave Week, 2000, 4 pages						
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